



7th International Workshop on Crystal Growth Technology

July 2-6, 2017

Potsdam (Berlin), Germany

PRELIMINARY ANNOUNCEMENT

The workshop—the seventh of a series initiated by Hans Scheel in 1998—is devoted to **Crystal Growth Technology**, industrial crystal growth technologies and equipment. The focus lies on preparation of bulk and substrate crystals.

Lecture topics of the workshop will include:

- Industrial growth technology of silicon and III-Vs (for electronics and photovoltaics)
- Growth technology for oxide and dielectric crystals (for piezoelectrics, lasers, scintillators, etc.)
- Wide band gap semiconductor substrates (sapphire, GaN, AlN, oxide electronics, etc.)
- Emerging fields and technologies in crystal growth
- Crucible and equipment technologies
- Raw materials, recycling, and efficiency issues

More information will be available soon at

<http://iwcgt-7.ikz-berlin.de/>

Conference Contact:

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Important Dates:

Jan 1, 2017	Registration/abstract submission starts
Mar 1, 2017	Poster abstract submission deadline
Mar 20, 2017	Abstract acceptance notification
Apr 15, 2017	Early registration ends
June 2017	Workshop in Berlin, Germany

The workshop links R&D to the actual production, bridging science and practice. International experts will present topical lectures with enough additional time for discussions and debate. The workshop will also comprise panel discussions and poster sessions, including a DGKK poster prize. **Meet the experts in crystal growth technology at IWC GT-7!**

Conference Chairs and Steering Committee:

Matthias Bickermann, IKZ Berlin, Germany (Chair)
Kazuo Nakajima, Tohoku Univ., Japan (Vice Chair)
Hanna Dabkowska, McMaster Univ., Canada (Vice Chair)
Edith D. Bourret-Courchesne, LLNL, USA
Peter Capper, SELEX Galileo Infrared, UK
Mitch Chou, National Sun Yat-Sen Univ., Taiwan
Ben Depuydt, Umicore, Belgium
Jeffrey J. Derby, Univ. Minnesota, USA
Ernesto Diéguez Delgado, Univ. Autónoma Madrid, Spain
Thierry Duffar, INP Grenoble, France
Roberto Fornari, Univ. Parma, Italy
Vincent J. Fratello, Integrated Photonics Inc., USA

Jochen Friedrich, Fraunhofer IISB, Germany
Olexander Gektin, Inst. Single Crystals, Kharkov, Ukraine
Koichi Kakimoto, Kyushu Univ., Japan
Frank M. Kießling, IKZ Berlin, Germany
Chung-Wen Lan, National Taiwan Univ., Taiwan
Yusuke Mori, Osaka Univ., Japan
Maria Porrini, SunEdison Semiconductors, Italy
Hans J. Scheel, Switzerland
Peter G. Schunemann, BAE Systems, USA
Nathan Stoddard, SolarWorld, USA
Deren Yang, State Key Lab., Zhejiang Univ., China
Evgenii V. Zharikov, D. Mendeleev Univ., Moscow, Russia

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of Crystal Growth



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Organisation of Crystal Growth (IOCG)

Organized by the
Leibniz Institute for
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